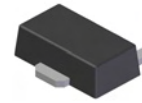




**Features**

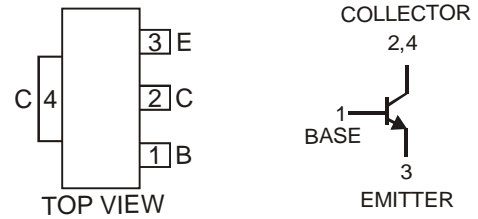
- Epitaxial Planar Die Construction
- Low Collector-Emitter Saturation Resistance  $R_{CE(SAT)} = 75m\Omega$  at 4A
- Complementary PNP Type Available (2DB1386)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**



SOT89-3L

**Mechanical Data**

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish — Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.072 grams (approximate)



Schematic and Pin Configuration

**Maximum Ratings** @  $T_A = 25^\circ C$  unless otherwise specified

| Characteristic               | Symbol    | Value | Unit |
|------------------------------|-----------|-------|------|
| Collector-Base Voltage       | $V_{CBO}$ | 50    | V    |
| Collector-Emitter Voltage    | $V_{CEO}$ | 20    | V    |
| Emitter-Base Voltage         | $V_{EBO}$ | 6     | V    |
| Peak Pulse Current           | $I_{CM}$  | 10    | A    |
| Continuous Collector Current | $I_C$     | 5     | A    |

**Thermal Characteristics**

| Characteristic  | Symbol          | Value       | Unit         |
|---|-----------------|-------------|--------------|
| Power Dissipation (Note 3) @ $T_A = 25^\circ C$                           | $P_D$           | 1           | W            |
| Thermal Resistance, Junction to Ambient Air (Note 3) @ $T_A = 25^\circ C$ | $R_{\theta JA}$ | 125         | $^\circ C/W$ |
| Operating and Storage Temperature Range                                   | $T_J, T_{STG}$  | -55 to +150 | $^\circ C$   |

**Electrical Characteristics** @  $T_A = 25^\circ C$  unless otherwise specified

| Characteristic                       | Symbol        | Min | Typ | Max | Unit    | Conditions                             |
|--------------------------------------|---------------|-----|-----|-----|---------|--|
| <b>OFF CHARACTERISTICS (Note 4)</b>  |               |     |     |     |         |  |
| Collector-Base Breakdown Voltage     | $V_{(BR)CBO}$ | 50  | —   | —   | V       | $I_C = 50\mu A, I_E = 0$               |
| Collector-Emitter Breakdown Voltage  | $V_{(BR)CEO}$ | 20  | —   | —   | V       | $I_C = 1mA, I_B = 0$                   |
| Emitter-Base Breakdown Voltage       | $V_{(BR)EBO}$ | 6   | —   | —   | V       | $I_E = 50\mu A, I_C = 0$               |
| Collector Cut-Off Current            | $I_{CBO}$     | —   | —   | 0.5 | $\mu A$ | $V_{CB} = 40V, I_E = 0$                |
| Emitter Cut-Off Current              | $I_{EBO}$     | —   | —   | 0.5 | $\mu A$ | $V_{EB} = 5V, I_C = 0$                 |
| <b>ON CHARACTERISTICS (Note 4)</b>   |               |     |     |     |         |  |
| Collector-Emitter Saturation Voltage | $V_{CE(SAT)}$ | —   | 0.3 | 1.0 | V       | $I_C = 4A, I_B = 0.1A$                 |
| DC Current Gain                      | $h_{FE}$      | 180 | —   | 390 | —       | $I_C = 0.5A, V_{CE} = 2V$              |
| <b>SMALL SIGNAL CHARACTERISTICS</b>  |               |     |     |     |         |  |
| Transition Frequency                 | $f_T$         | —   | 220 | —   | MHz     | $V_{CE} = 6V, I_E = -50mA, f = 100MHz$ |
| Output Capacitance                   | $C_{ob}$      | —   | 14  | —   | pF      | $V_{CB} = 20V, I_E = 0, f = 1MHz$      |

- Notes:
1. No purposefully added lead.
  2. Diodes Inc.'s "Green" policy can be found on our website at [http://www.diodes.com/products/lead\\_free/index.php](http://www.diodes.com/products/lead_free/index.php).
  3. Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
  4. Measured under pulsed conditions. Pulse width = 300 $\mu s$ . Duty cycle  $\leq 2\%$ .

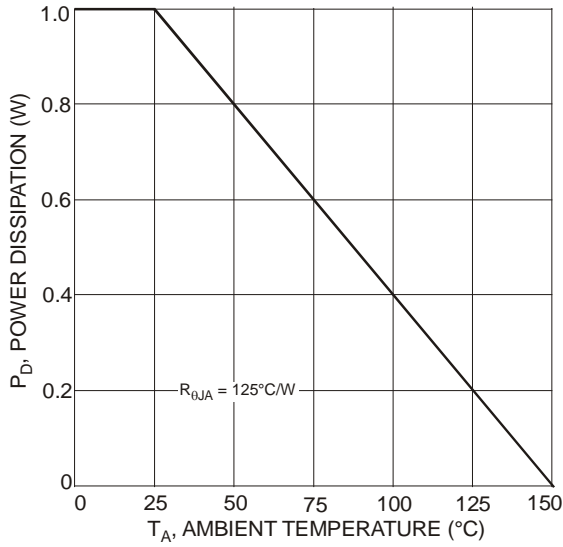


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)

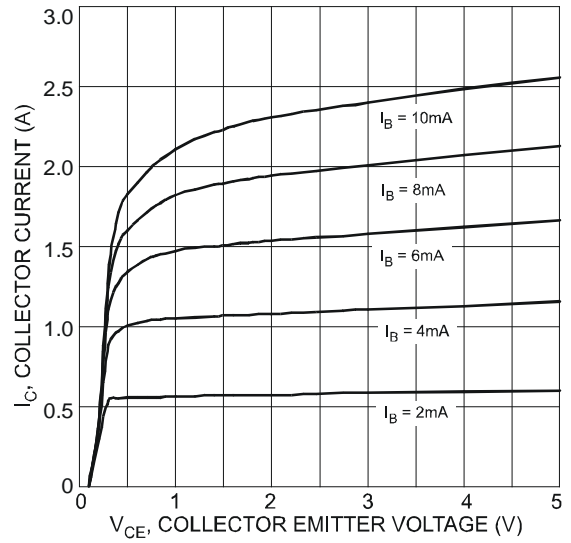


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage

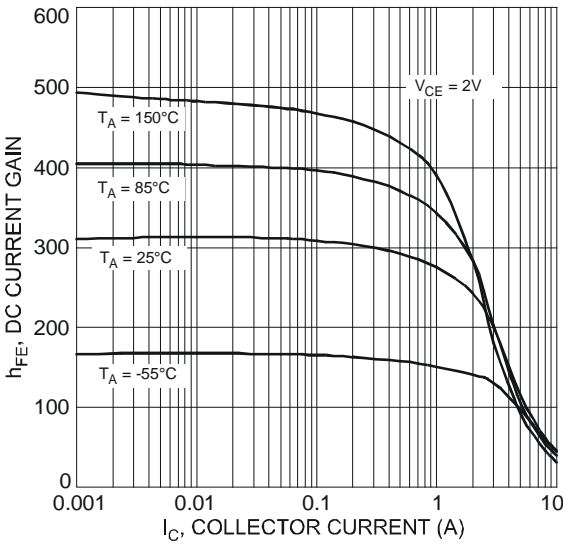


Fig. 3 Typical DC Current Gain vs. Collector Current

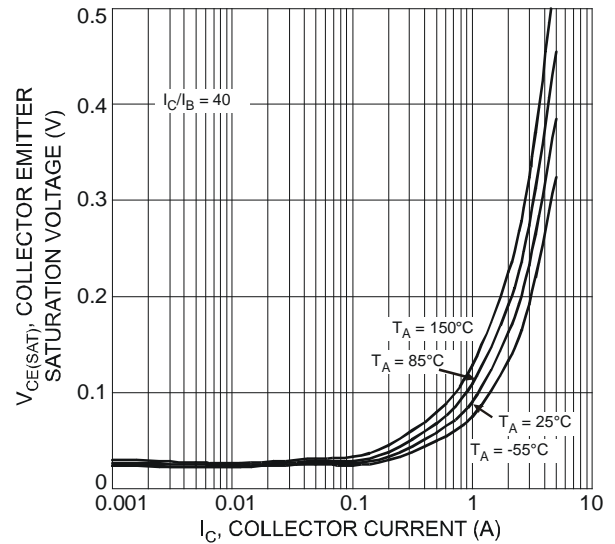


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

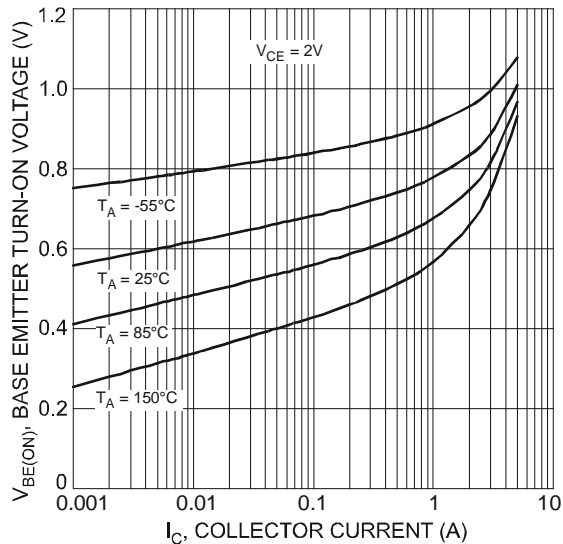


Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

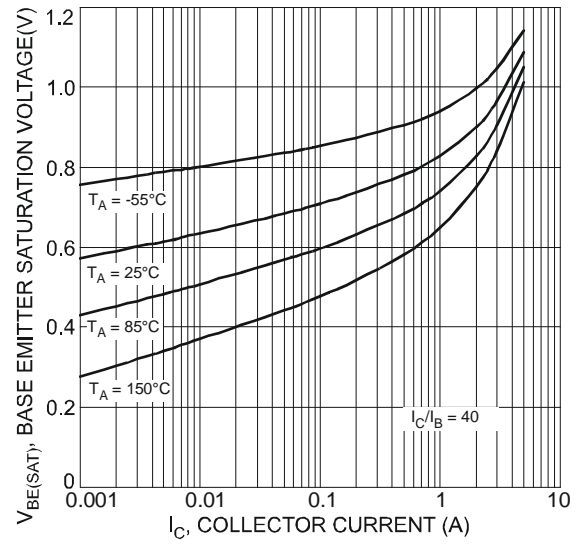


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

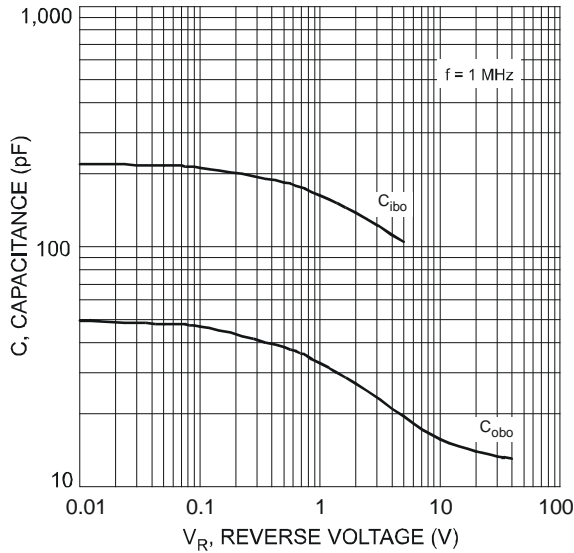


Fig. 7 Typical Junction Capacitance Characteristics

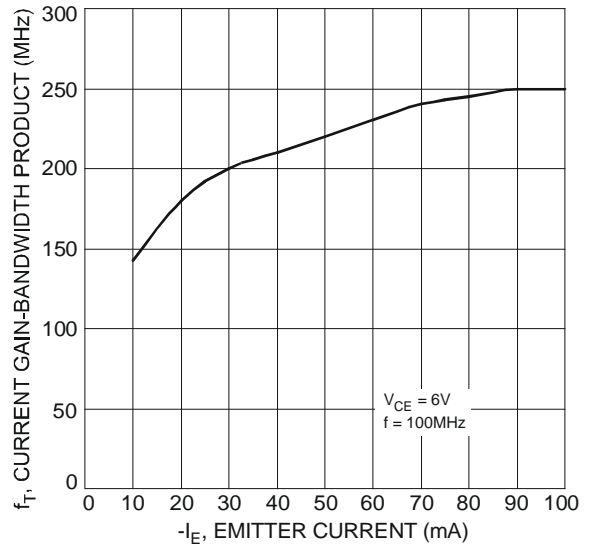


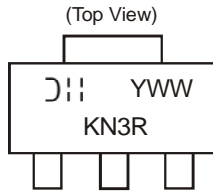
Fig. 8 Typical Gain-Bandwidth Product vs. Emitter Current

## Ordering Information (Note 5)

| Device      | Packaging | Shipping         |
|-------------|-----------|------------------|
| 2DD2098R-13 | SOT89-3L  | 2500/Tape & Reel |

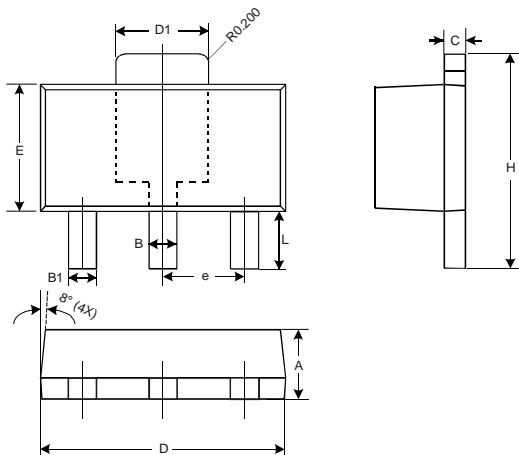
Notes: 5. For packaging details, please see below or go to our website at <http://www.diodes.com/ap02007.pdf>.

## Marking Information



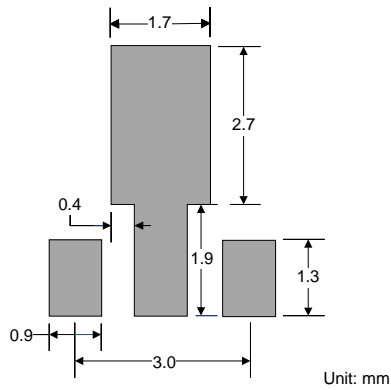
KN3R = Product Type Marking Code  
 DII = Manufacturer's Marking Code  
 YWW = Date Code Marking  
 Y = Last digit of year ex: 7 = 2007  
 WW = Week code 01 - 52

## Package Outline Dimensions



| SOT89-3L             |      |      |      |
|----------------------|------|------|------|
| Dim                  | Min  | Max  | Typ  |
| A                    | 1.40 | 1.60 | 1.50 |
| B                    | 0.45 | 0.55 | 0.50 |
| B1                   | 0.37 | 0.47 | 0.42 |
| C                    | 0.35 | 0.43 | 0.38 |
| D                    | 4.40 | 4.60 | 4.50 |
| D1                   | 1.50 | 1.70 | 1.60 |
| E                    | 2.40 | 2.60 | 2.50 |
| e                    | —    | —    | 1.50 |
| H                    | 3.95 | 4.25 | 4.10 |
| L                    | 0.90 | 1.20 | 1.05 |
| All Dimensions in mm |      |      |      |

## Suggested Pad Layout



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